## NSN 5961-00-912-6844

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View Online at https://aerobasegroup.com/nsn/5961-00-912-6844 **Inclosure Material:** Metal **Overall Length:** 2.500 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 gate trigger voltage, dc and 1.8 on-state voltage, dc **Current Rating Per Characteristic:** 130.00 milliamperes forward current, total rms preset and 70.00 amperes forward current, total rms nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 62.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 insulated wire lead w/terminal lug **Specification Data:** 80131-release4287 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0